NSN 5961-01-173-7632

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-173-7632 **Inclosure Material:** Metal **Overall Length:** 3.000 inches **Overall Height:** 0.650 inches **Overall Width:** 1.000 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 reverse voltage, peak **Current Rating Per Characteristic:** 2.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 threaded hole Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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